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# 74HC3G34; 74HCT3G34

Triple buffer gate

Rev. 6 — 11 December 2013

**Product data sheet** 

#### 1. **General description**

The 74HC3G34; 74HCT3G34 is a triple buffer. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V<sub>CC</sub>.

#### **Features and benefits** 2.

- Wide supply voltage range from 2.0 V to 6.0 V
- Input levels:
  - ◆ For 74HC3G34: CMOS level
  - ◆ For 74HCT3G34: TTL level
- Complies with JEDEC standard no. 7 A
- Symmetrical output impedance
- High noise immunity
- Low-power dissipation
- Balanced propagation delays
- Multiple package options
- ESD protection:
  - HBM JESD22-A114E exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

#### **Ordering information** 3.

Table 1. **Ordering information** 

Type number	Package								
	Temperature range	Name	Description	Version					
74HC3G34DP				SOT505-2					
74HCT3G34DP			body width 3 mm; lead length 0.5 mm						
74HC3G34DC	–40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads;	SOT765-1					
74HCT3G34DC			body width 2.3 mm						
74HC3G34GD	–40 °C to +125 °C	XSON8 plastic extremely thin small outline package; no leads;		places of the pl		SOT996-2			
74HCT3G34GD			8 terminals; body $3 \times 2 \times 0.5$ mm						



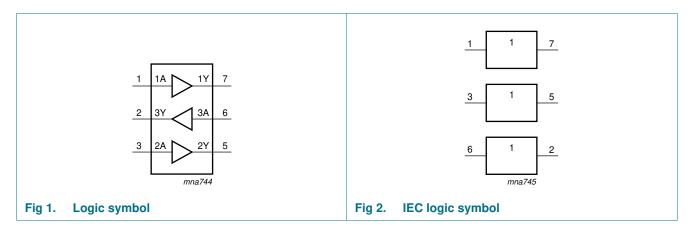
## 4. Marking

Table 2. Marking

3	
Type number	Marking code <sup>[1]</sup>
74HC3G34DP	H34
74HCT3G34DP	T34
74HC3G34DC	P34
74HCT3G34DC	U34
74HC3G34GD	P34
74HCT3G34GD	U34

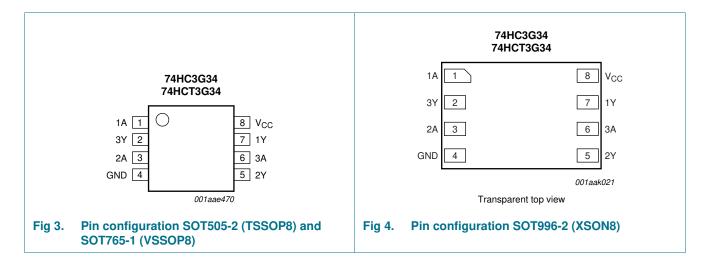
<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

## 5. Functional diagram



## 6. Pinning information

### 6.1 Pinning



## 6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
1A, 2A, 3A	1, 3, 6	data input
1Y, 2Y, 3Y	7, 5, 2	data output
GND	4	ground (0 V)
V <sub>CC</sub>	8	supply voltage

## 7. Functional description

Table 4. Function table [1]

Input	Output
nA	nY
L	L
Н	Н

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level.

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> -	±20	mA
I <sub>OK</sub>	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> -	±20	mA
Io	output current	$V_O = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-	±25	mA
I <sub>CC</sub>	quiescent supply current		-	50	mA
$I_{GND}$	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$	[2] _	300	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>[2]</sup> For TSSOP8 package: above 55 °C the value of  $P_{tot}$  derates linearly with 2.5 mW/K. For VSSOP8 package: above 110 °C the value of  $P_{tot}$  derates linearly with 8 mW/K. For XSON8 package: above 118 °C the value of  $P_{tot}$  derates linearly with 7.8 mW/K.

## 9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol Parameter Conditions		Conditions	74HC3G34		74HCT3G34			Unit	
			Min	Тур	Max	Min	Тур	Max	
$V_{CC}$	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	$V_{CC}$	0	-	$V_{CC}$	V
Vo	output voltage		0	-	$V_{CC}$	0	-	$V_{CC}$	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t/\Delta V$	input transition rise	$V_{CC} = 2.0 \text{ V}$	-	-	625	-	-	-	ns/V
	and fall rate	$V_{CC} = 4.5 \text{ V}$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}$	-	-	83	-	-	-	ns/V

## 10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C	-40 °C to +125 °C		
			Min	Typ[1]	Max	Min	Max		
74HC3G3	34		1	'		1			
$V_{IH}$	HIGH-level input voltage	$V_{CC} = 2.0 \text{ V}$	1.5	1.2	-	1.5	-	V	
		V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	V	
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	V	
$V_{IL}$	LOW-level input	V <sub>CC</sub> = 2.0 V	-	8.0	0.5	-	0.5	V	
	voltage	V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	V	
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	V	
$V_{OH}$	HIGH-level output	$V_I = V_{IH}$ or $V_{IL}$							
	voltage	$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	V	
		$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	V	
		$I_{O} = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	V	
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	4.13	4.32	-	3.7	-	V	
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.63	5.81	-	5.2	-	V	
$V_{OL}$	LOW-level output	$V_I = V_{IH}$ or $V_{IL}$							
	voltage	$I_{O} = 20 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	V	
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	V	
		$I_O = 20 \mu A; V_{CC} = 6.0 V$	-	0	0.1	-	0.1	V	
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.33	-	0.4	V	
		$I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.33	-	0.4	V	
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±1.0	-	±1.0	μА	
I <sub>CC</sub>	supply current	per input pin; $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	10	-	20	μΑ	
Cı	input capacitance		-	1.5	-	-	-	pF	

**Table 7. Static characteristics** ...continued Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	–40 °C t	Unit	
			Min	Typ[1]	Max	Min	Max	
<b>74HCT3G</b>	34		'					
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	1.6	-	2.0	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	1.2	8.0	-	8.0	V
$V_{OH}$	HIGH-level output	$V_I = V_{IH}$ or $V_{IL}$						
	voltage	$I_O = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	4.13	4.32	-	3.7	-	V
$V_{OL}$	LOW-level output	$V_I = V_{IH}$ or $V_{IL}$						
	voltage	$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.33	-	0.4	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	-	±1.0	μА
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	10	-	20	μΑ
$\Delta I_{CC}$	additional supply current	per input; $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V};$ $V_I = V_{CC} - 2.1 \text{ V};$ $I_O = 0 \text{ A}$	-	-	375	-	410	μΑ
Cı	input capacitance		-	1.5	-	-	-	рF

<sup>[1]</sup> All typical values are measured at  $T_{amb}$  = 25 °C.

## 11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 6.

Symbol	Parameter	Conditions		-40	°C to +85	5 °C	–40 °C t	o +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
74HC3G	34	'					'	'	
t <sub>pd</sub>	propagation delay	nA to nY; see Figure 5	[2]						
		$V_{CC} = 2.0 \text{ V}$		-	29	95	-	125	ns
		$V_{CC} = 4.5 \text{ V}$		-	9	19	-	25	ns
		$V_{CC} = 6.0 \text{ V}$		-	8	16	-	20	ns
t <sub>t</sub>	transition time	nY; see Figure 5	[3]						
		$V_{CC} = 2.0 \text{ V}$		-	18	95	-	125	ns
		$V_{CC} = 4.5 \text{ V}$		-	6	19	-	25	ns
		$V_{CC} = 6.0 \text{ V}$		-	5	16	-	20	ns
$C_PD$	power dissipation capacitance	$V_I = GND$ to $V_{CC}$	[4]	-	10	-	-	-	pF

 Table 8.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 6.

Symbol Parameter		Conditions		–40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max		
74HCT30	G34		,						
t <sub>pd</sub> propagation delay		nA to nY; see Figure 5	[2]						
		V <sub>CC</sub> = 4.5 V		-	10	23	-	29	ns
t <sub>t</sub>	transition time	nY; V <sub>CC</sub> = 4.5 V; see <u>Figure 5</u>	[3]	-	6	19	-	25	ns
$C_{PD}$	power dissipation capacitance	$V_I = GND \text{ to } V_{CC} - 1.5 \text{ V}$	[4]	-	9	-	-	-	pF

- [1] All typical values are measured at  $T_{amb} = 25$  °C.
- [2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .
- [3]  $t_t$  is the same as  $t_{TLH}$  and  $t_{THL}$ .
- [4]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o) \text{ where:}$ 

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

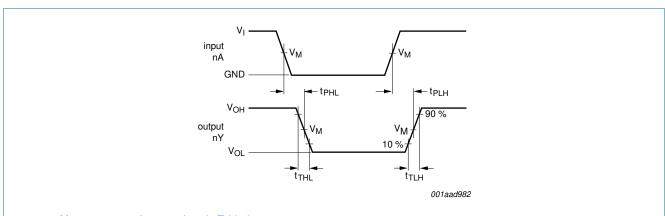
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

### 12. Waveforms



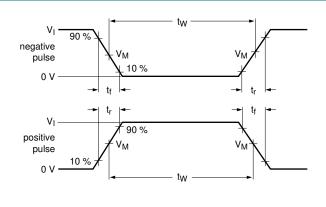
Measurement points are given in Table 9.

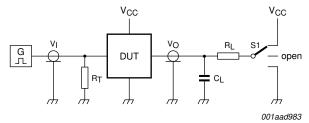
Fig 5. Propagation delay data input (nA) to data output (nY) and transition time output (nY)

Table 9. Measurement points

Туре	Input	Output
	V <sub>M</sub>	V <sub>M</sub>
74HC3G34	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
74HCT3G34	1.3 V	1.3 V

74HC\_HCT3G34





Test data is given in Table 10.

Definitions for test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

 $C_L$  = Load capacitance including jig and probe capacitance.

R<sub>L</sub> = Load resistance.

S1 = Test selection switch.

Fig 6. Test circuit for measuring switching times

Table 10. Test data

Туре	Input Load		Load		S1 position
	V <sub>I</sub>	t <sub>r</sub> , t <sub>f</sub>	C <sub>L</sub>	R <sub>L</sub>	t <sub>PHL</sub> , t <sub>PLH</sub>
74HC3G34	GND to V <sub>CC</sub>	≤ 6 ns	50 pF	1 kΩ	open
74HCT3G34	GND to 3 V	≤ 6 ns	50 pF	1 kΩ	open

## 13. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm SOT505-2

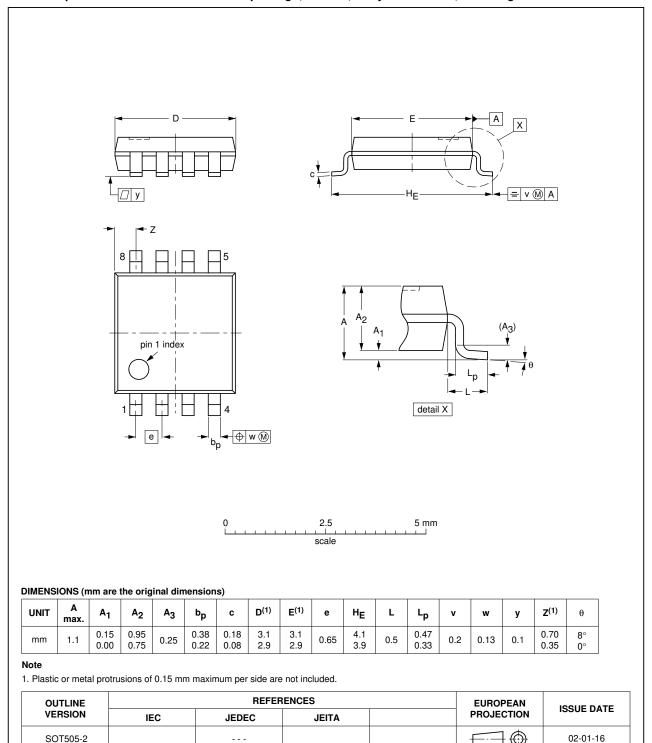
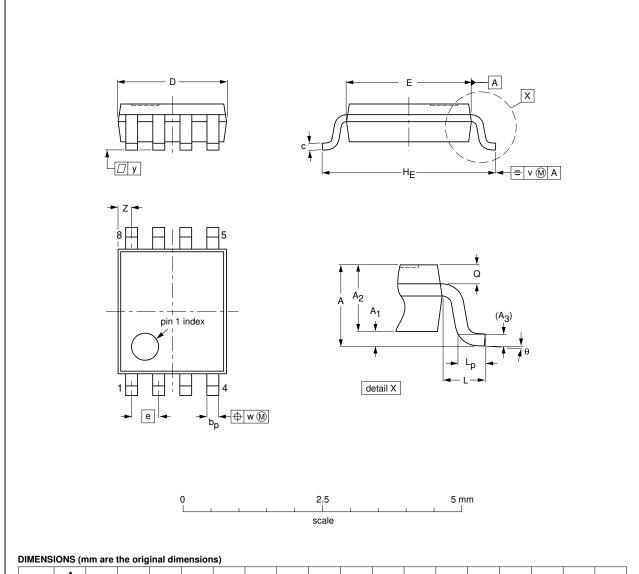


Fig 7. Package outline SOT505-2 (TSSOP8)

### VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1	0.15 0.00	0.85 0.60	0.12	0.27 0.17	0.23 0.08	2.1 1.9	2.4 2.2	0.5	3.2 3.0	0.4	0.40 0.15	0.21 0.19	0.2	0.13	0.1	0.4 0.1	8° 0°

#### Notes

Plastic or metal protrusions of 0.15 mm maximum per side are not included.
 Plastic or metal protrusions of 0.25 mm maximum per side are not included.

	OUTLINE		REFER	EUROPEAN	ISSUE DATE			
	VERSION	IEC	JEDEC	JEITA		PROJECTION	1330E DATE	
	SOT765-1		MO-187				02-06-07	
٠								

Fig 8. Package outline SOT765-1 (VSSOP8)

74HC\_HCT3G34

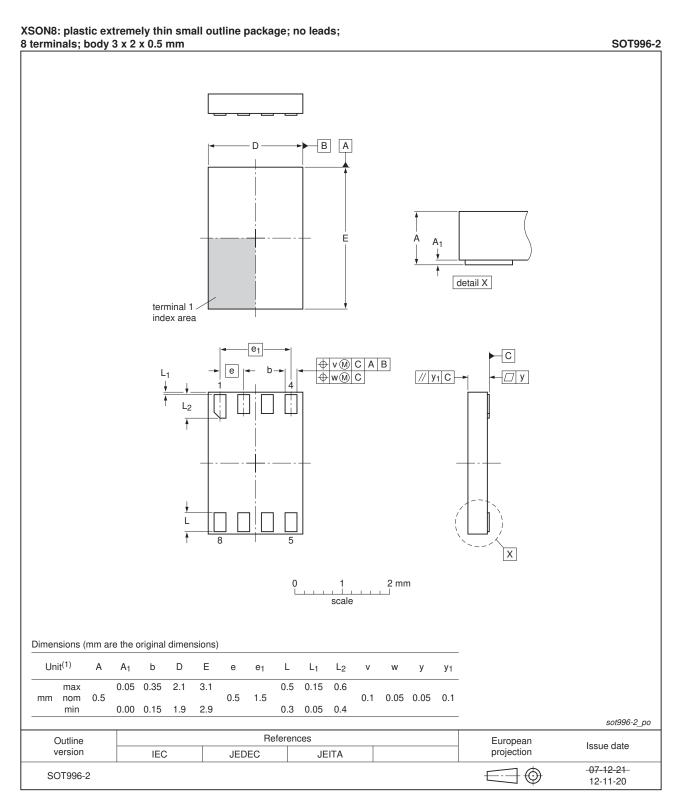


Fig 9. Package outline SOT996-2 (XSON8)

74HC\_HCT3G34

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## 14. Abbreviations

### Table 11. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

## 15. Revision history

#### Table 12. Revision history

	,			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT3G34 v.6	20131211	Product data sheet	-	74HC_HCT3G34 v.5
Modifications:	<ul> <li>For type nu</li> </ul>	mbers 74HC3G34GD and 7	4HCT3G34GD XSON8	U has changed to XSON8.
74HC_HCT3G34 v.5	20090507	Product data sheet	-	74HC_HCT3G34 v.4
74HC_HCT3G34 v.4	20060309	Product data sheet	-	74HC_HCT3G34 v.3
74HC_HCT3G34 v.3	20030519	Product specification	-	74HC_HCT3G34 v.2
74HC_HCT3G34 v.2	20030210	Product specification	-	74HC_HCT3G34 v.1
74HC_HCT3G34 v.1	20031003	Product specification	-	-

## 16. Legal information

#### 16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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### 17. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

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